

TX-3570WG30FSB3-NU3CD-01

PRODUCT SPECIFICATION

Features:

- ◆Excellent transiting heat from LED chip operating under 1900mA.
- ◆Ceramic eutectic package allows it to have minimal internal stress and excellent thermal path.
- ◆Flip chip coated with package, the output of lumen is stable.
- ◆High luminous output.
- ◆Encapsulated materials are environmentally certified and meet environmental requirements.

Chip Material:

- ◆GaN
- ◆GaN

Emitting Color:

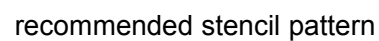
- ◆Cold white
- ◆Golden yellow

Applications:

- ◆Automobile lighting

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Figure 1: Dimensions of the device. The figure consists of three views: Top view, Side view, and Bottom view. The Top view shows a rectangular device with a central yellow area divided into six segments (three yellow, three orange) and a grey border. Dimensions include W+, G+, W-, G-, 3.03, 3.50, 4.40, and 7.00. The Side view shows the thickness of the device, with dimensions 0.7 and 0.40. The Bottom view shows the underside of the device with a large yellow central area and grey borders. Dimensions include 5.10, 0.60, 1.35, 3.30, 5.90, 0.45, 6.80, and 0.7. A label 'Anode' points to a small yellow rectangle in the top left corner of the Bottom view.



- 1.All dimensions are in millimeters .
- 2.Tolerances unless otherwise mentioned are $\pm 0.1\text{mm}$.

Version:1.0

Absolute Maximum Ratings (Tc=25℃)

Parameter	Symbol		Ratings	Unit
Forward Current	IF	W	1900	mA
		G	1900	
Reverse Voltage	VR		Not designed for reverse operation	V
Power Dissipation	PD		30	W
Junction Temperature	Tj		150	℃
Electrostatic Discharge Threshold (ESD)	ESD		2000	V
Storage Temperature	Tstg		-40~+70	℃
Operation Temperature	Topr		-30~+125	

Notes:

1.Specifications are subject to change without notice.

2.The data on this specification is for reference only and the actual data is in accordance with the acknowledgment.

3.Precautions for ESD:

STATIC SHIELD Electricity and surge damages the LED. It is recommended to use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

Electrical Optical Characteristics (Tc=25°C)

Parameter	Symbol	Condition	Emitting color	Min.	Typ.	Max.	Units
Luminous Flux	Φ_v	If=1600mA	W	1650	1750	1950	lm
			G	1700	1800	1950	
Forward Voltage	V_f	If=1600mA	W	8.8	9.4	9.8	V
			G	8.8	9.4	9.8	
Correlated Colour Temperature	CCT	If=1000mA	W	5500	6250	6900	K
			G	3120	3200	3300	
Viewing Angle at 50 % IV	$2\theta_{1/2}$	—	W	—	120	—	Deg
			G	—	120	—	
Reverse Current	I_R	—	W	—	—	—	μA
			G	—	—	—	
Thermal Resistance Junction to Case	$R_{\theta J-C}$	If=1600mA	—	—	0.4	—	K/W
Temperature Coefficient of Voltage	$V_{\Delta F/T}$		—	—	-6	—	mV/°C

Golden yellow Color coordinate filing (IF=1000mA)

Region	CCT Range		X1	Y1	X2	Y2	X3	Y3	X4	Y4
	Min	Max								
03	3120K	3200K	0.4740	0.5020	0.4655	0.4990	0.4684	0.5105	0.4778	0.5142
01	3200K	3300K	0.4650	0.4971	0.4552	0.4929	0.4582	0.5050	0.4680	0.5090

White Color coordinate filing (IF=1000mA)

Region	CCT Range		X1	Y1	X2	Y2	X3	Y3	X4	Y4
	Min	Max								
G12	5500K	5700K	0.3322	0.3612	0.3274	0.3516	0.3270	0.3672	0.3323	0.3763
G10	5700K	6000K	0.3275	0.3506	0.3216	0.3374	0.3205	0.3523	0.3270	0.3662
F01	6000K	6500K	0.3216	0.3364	0.3141	0.3196	0.3123	0.3336	0.3206	0.3513
E11	6500K	6900K	0.3143	0.3185	0.3118	0.3129	0.3096	0.3265	0.3124	0.3326

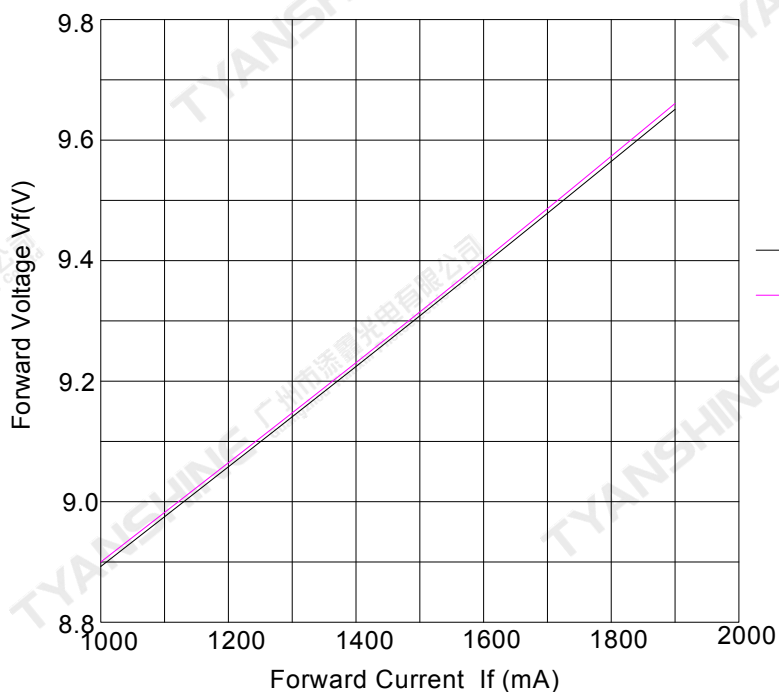
Notes:

- 1.Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.
2. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3.The dominant wavelength (λ_d) is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
- 4.Luminous flux measurement tolerance: $\pm 15\%$.
- 5.Forward voltage measurement tolerance: $\pm 0.15V$.

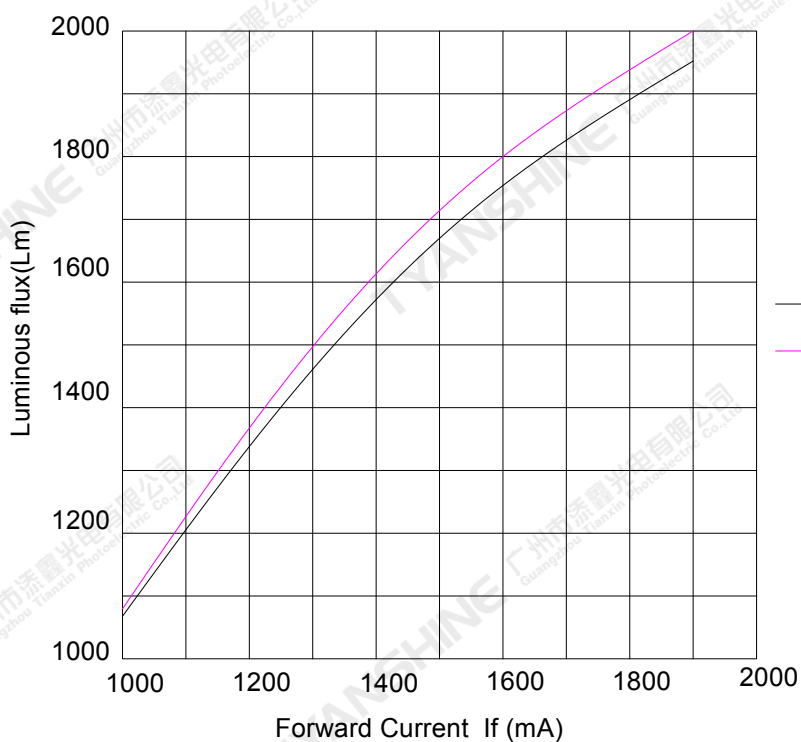
Typical Electrical/Optical Characteristics Curves

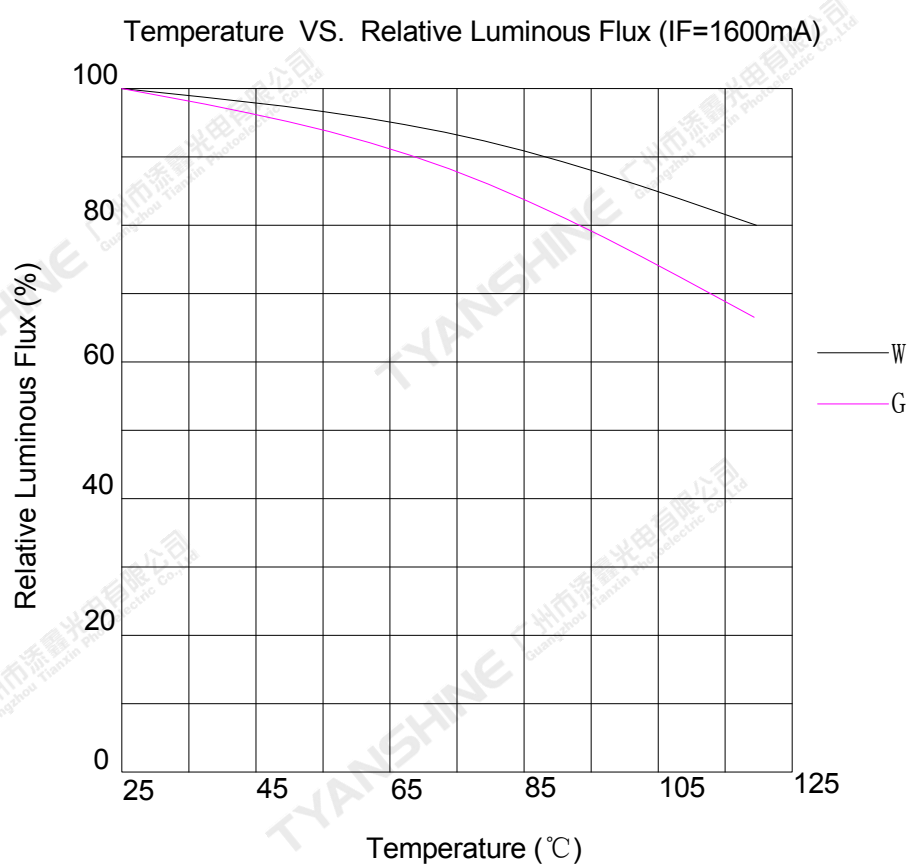
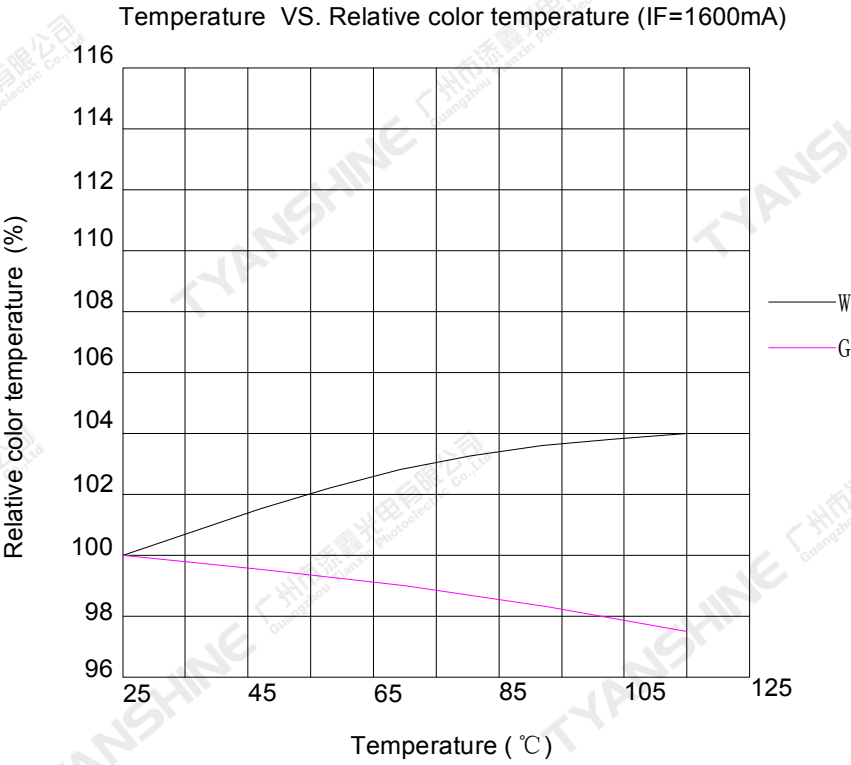
(25°C Ambient Temperature Unless Otherwise Noted)

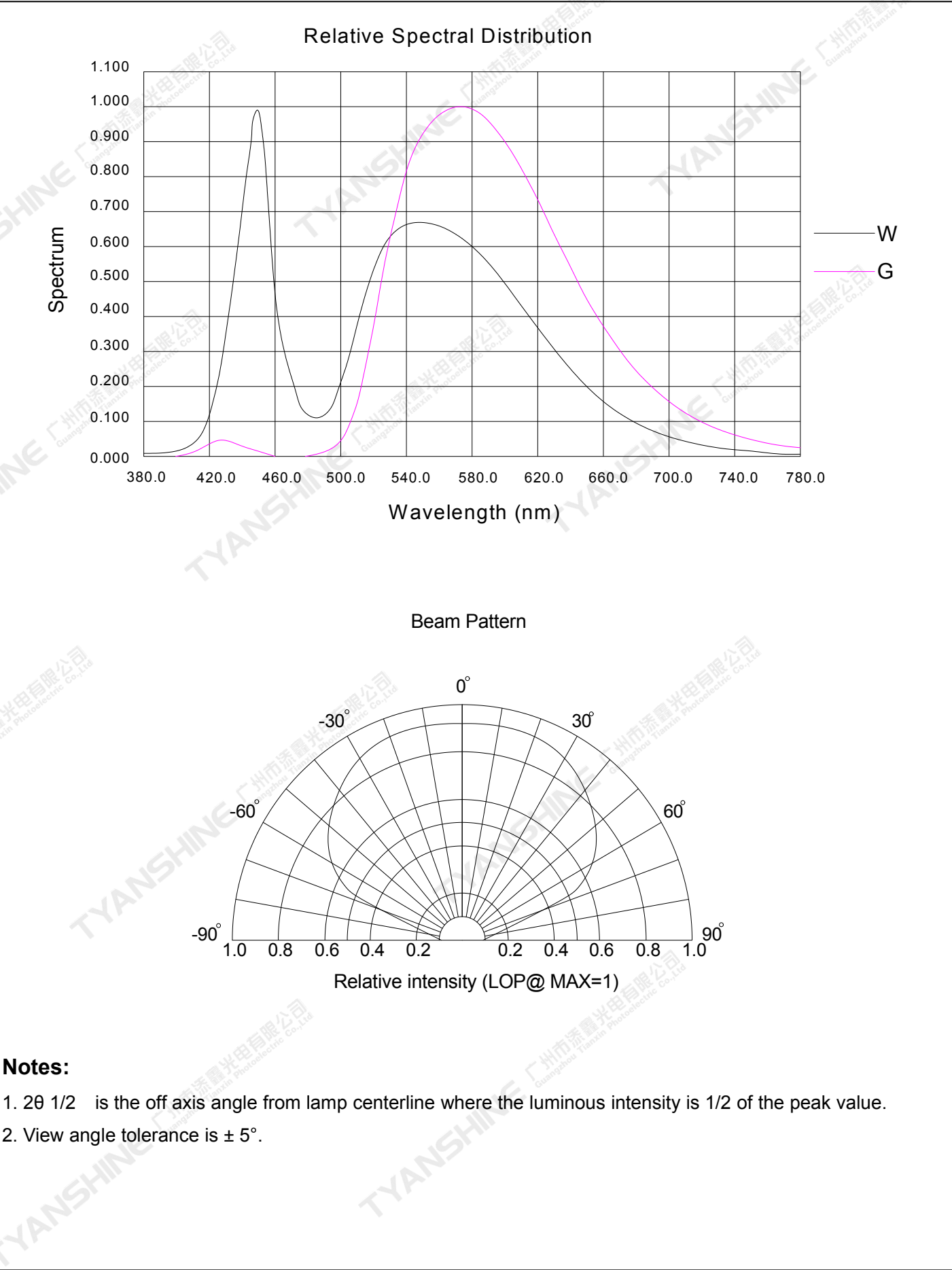
Forward Current VS. Forward Voltage



Forward Current VS. Luminous flux







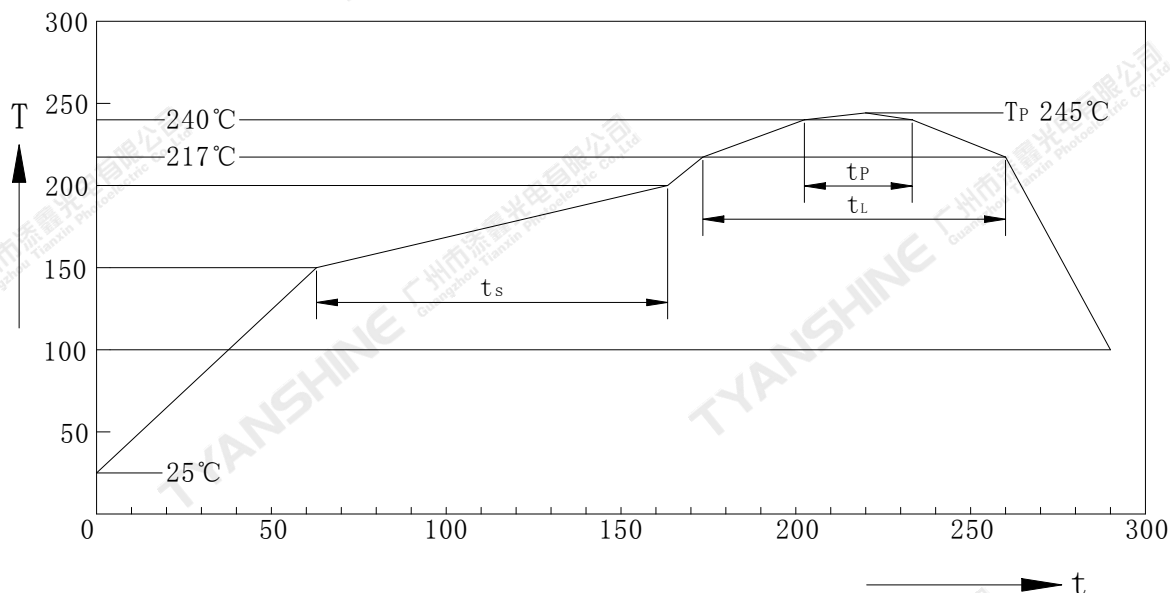
Usage Precautions

Storage Environment Condition

Temperature: 5°C ~ 30°C (41°F ~ 86°F)

Humidity: 60% RH Max.

Soldering Condition



Profil-Charakteristik Profile Feature	Symbol	Pb-Free(SnAgCu)Assembly			Einheit Unit
		Minimum	Recommendation	Maximum	
Ramp-up Rate to Preheat 25°C to 150°C	-	-	2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t_s	60	100	120	s
Ramp-up Rate to Peak T_{Smax} to T_p	-	-	2	3	K/s
Liquidus Temperature	T_L	217			°C
Time above Liquidus temperature	t_L	-	80	100	s
Peak Temperature	T_P	-	245	260	°C
Time within 5°C of the specified peak temperature $T_p \pm 5$ K	t_P	10	20	30	s
Ramp-down Rate T_p to 100°C	-	-	3	6	K/s
Time 25°C to T_p	-	-	-	480	-

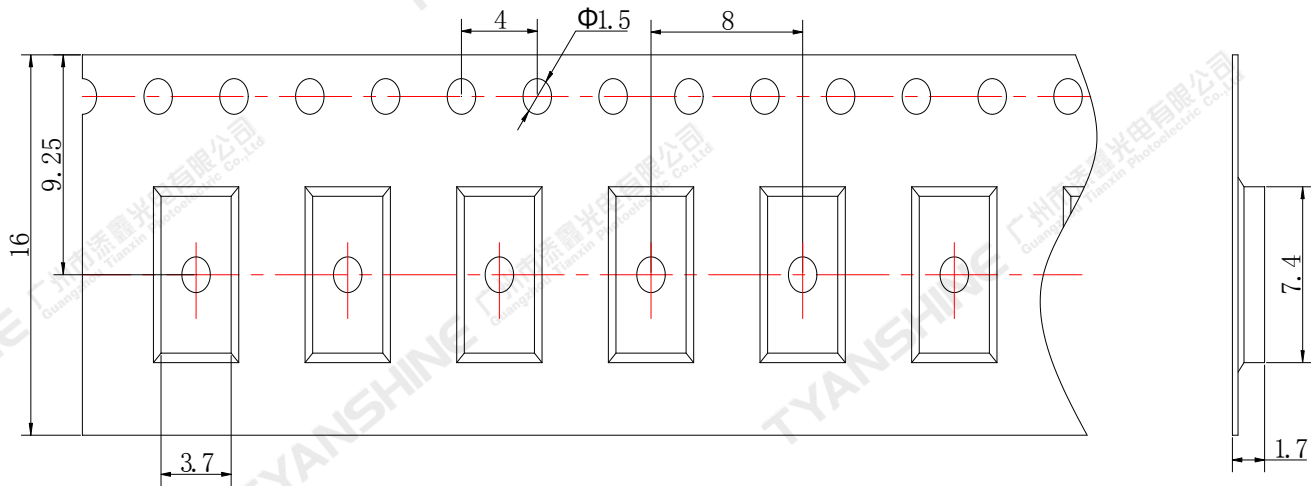
Note:

All temperatures refer to topside of the package, measured on the package body surface.

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Dimensions For Cannulation And Packaging

Quantity: 1000PCS



Notes:

1. All dimensions are in millimeters.
2. Tolerances are ± 2.0 mm unless otherwise noted.
3. The products are packaged together with silica gel, Transport, not to the weight of welding LED light-emitting area, As a result of the weight of LED light-emitting zone in the quality of, Irresponsible of the Company.